A highly efficient (>6%) \( \text{Cd}_{1-x}\text{Mn}_x\text{Se} \) quantum dot sensitized solar cell

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Quantum dot sensitized solar cells (QDSCs) have attracted considerable attention recently and become promising candidates for realizing a cost-effective solar cell. The design and synthesis of quantum dots (QDs) for achieving high photoelectric performance is an urgent need imposed on scientists. Here, we have succeeded in designing a QDSC with a high efficiency \( \eta \) of 6.33% based on \( \text{Cd}_{0.8}\text{Mn}_{0.2}\text{Se} \) quantum dots by facile chemical bath deposition (CBD). The effects of \( \text{Mn}^{2+} \) ions on the physical, chemical, and photovoltaic properties of the QDSCs are investigated. The \( \text{Mn}^{2+} \) ions doped into QDs can increase the light harvesting to produce more excitons. In addition, the \( \text{Mn}^{2+} \) dopant also raises the conduction band of CdSe, accelerates the electron injection kinetics and reduces the charge recombination, improving the charge transfer and collection. The increase of the efficiencies of light-harvesting, charge-transfer and charge-collection results in the improvement of the quantum efficiency of the solar cells. The power conversion efficiency of the solar cell is increased to 6.33% \( (V_{\text{oc}} = 0.58 \, \text{V}, J_{\text{sc}} = 19.15 \, \text{mA cm}^{-2}, \) and FF \( = 0.57) \).

1. Introduction

Developing low-cost and high-performance solar devices for clean energy sources is becoming an increasingly urgent issue imposed on scientists around the world, as conventional photovoltaic devices, namely crystalline silicon (c-Si) solar cells, suffer from high cost of manufacturing and installation. Now the focus is on next generation solar cells with high efficiency at economically viable cost.\textsuperscript{1,2} Semiconductor quantum dots (QDs) are drawing great attention as a material for next generation solar cells due to their high absorption coefficient, tunable band gap and multiple exciton generation (MEG) effect.\textsuperscript{3–5} So QDs have been used in dye sensitized solar cells (DSSCs) as the photo-sensitizer instead of organic dyes to form quantum dot sensitized solar cells (QDSCs).\textsuperscript{6–8} The typical structure of QDSCs is similar to that of DSSCs, which consists of a mesoporous photoanode (TiO\textsubscript{2} film), a sensitizer (QDs), an electrolyte (poly-sulfide) and a counter electrode (Cu\textsubscript{2}S).\textsuperscript{9–11} During operation, photons are captured by QDs, yielding electron–hole pairs that are rapidly separated into electrons and holes at the interface between the nanocrystalline TiO\textsubscript{2} and the QDs. The electrons inject into the TiO\textsubscript{2} film and the holes are released by redox couples in the liquid polysulfide electrolyte.\textsuperscript{9,12,13}

Improving the power conversion efficiency \( (\eta) \) of QDSCs has always been an overarching concern for all scientists. One of the approaches has been focused on constructing and fabricating nano-structural oxides, such as TiO\textsubscript{2},\textsuperscript{14} ZnO\textsuperscript{15,16} and SnO\textsubscript{2}\textsuperscript{16} to harvest more amounts of QDs. On the other hand, many efforts have been concentrated on designing and synthesizing QDs to achieve high photoelectric performance.\textsuperscript{17–19} As for colloidal QDs, doping transition metal ions would lead to new materials showing fascinating electronic and photo-physical properties of QDs.\textsuperscript{20–22} So the method of introducing doping metal ions into QDs is believed to be an effective method to improve the performance of QDSCs. Recently, a few studies showed that doping of some ions into sulfide QDs, such as Hg\textsuperscript{2+} into PbS,\textsuperscript{23} and Mn\textsuperscript{2+} into CdS,\textsuperscript{23} could increase the current density and efficiency of the solar cells. Compared with CdS and PbS QDs, CdSe is more attractive owing to its high potential for light harvesting in the visible light region.\textsuperscript{24–25} The efficiency of CdSe sensitized QDSCs is much higher than that of sulfide QD sensitized solar cells.\textsuperscript{17,26–30} So doping metal ions into CdSe QDs is thought to be a useful way for designing high efficiency solar cells.\textsuperscript{31,32} However, there is little research on the doped CdSe for QDSCs due likely to its difficult formation. In a typical process for the fabrication of QDSCs, QDs can be introduced via an approach of \textit{in situ} growth directly from the precursor solutions, which includes successive ionic layer absorption and reaction (SILAR)\textsuperscript{33} and chemical bath deposition (CBD).\textsuperscript{34} The preparation of CdSe QDs by SILAR needs to be carried out under inert conditions or at high temperature. Compared with SILAR, CBD is a relatively simple method to deposit nanoparticle films...
under ambient conditions, which possesses many advantages, such as stable yield, robust adherence, and uniform and good reproducibility. So CBD is believed to be an appropriate approach for depositing doped CdSe QDs. For transition metal ions, Mn$^{2+}$ is the most common dopant for colloidal QDs to improve the photoluminescence (PL) and quantum yield (QY) of QDs. The dopant creates electronic states in the mid-gap region of the QDs, and thus alters the charge separation and recombination. So, it should be advantageous to produce more excitons to enhance the quantum efficiency of the solar cells using a Mn$^{2+}$ dopant.

Here, we have succeeded in designing a high efficiency QDSC based on Cd$_{1-x}$Mn$_x$Se quantum dots. It was found that Cd$_{1-x}$Mn$_x$Se is difficult to deposit directly on the surface of TiO$_2$ oxides. For this reason, the modification of TiO$_2$ with CdS was adopted to improve the adsorption of Cd$_{1-x}$Mn$_x$Se to form a photoanode with the structure of TiO$_2$/CdS/Cd$_{1-x}$Mn$_x$Se. This investigation revealed that the doping of Mn$^{2+}$ into the CdSe QDs can significantly influence the performances, such as the light-harvesting, charge-transfer and charge-collection capabilities. As a result, the Cd$_{0.8}$Mn$_{0.2}$Se sensitized solar cell exhibited a high conversion efficiency of 6.33% under simulated AM 1.5, 100 mW cm$^{-2}$.

2. Results and discussion

Deposition of Cd$_{1-x}$Mn$_x$Se QDs is implemented by the CBD process in a solution containing 0.1 M sodium selenosulphate (Na$_2$SeSO$_3$), 0.1 M mixture of cadmium acetate Cd(CH$_2$COO)$_2$ and manganese acetate Mn(CH$_2$COO)$_2$, and 0.2 M trisodium salt of nitrilotriacetic acid (N(CH$_2$COONa)$_3$) at room temperature for 3 hours. During this process, the Mn$^{2+}$ cation substitutes the Cd$^{2+}$ in CdSe forming Cd$_{0.8}$Mn$_{0.2}$Se with a Mn to Cd atomic ratio of 8 : 2 in the reaction solution. The valence state of Mn in quantum dots is determined by X-ray photoelectron spectroscopy (XPS) spectra. Fig. 1 displays the XPS spectra of the nanostructured TiO$_2$ films loaded with Cd$_{0.8}$Mn$_{0.2}$Se QDs. The peak deconvolution process clearly shows that the Mn 2p spectrum of the film is composed of two peaks, at 642 eV and 654 eV, indicating the state of Mn$^{2+}$ in QDs. The composition ratios of Mn/Cd in Cd$_{0.8}$Mn$_{0.2}$Se QDs are calculated by energy-dispersive X-ray spectroscopy (EDX). The results of EDX are approximate to those of the ratios in the reaction solution.

Fig. 2(a) displays the UV-visible spectral curves of the films loaded with CdSe and Cd$_{0.8}$Mn$_{0.2}$Se QDs. The results reveal that the absorbance of the Cd$_{0.8}$Mn$_{0.2}$Se QDs is much higher than that of the CdSe QDs. The high absorbance of the photoelectrode might be attributed to: (1) a greater loading amount of QDs; and (2) the effects of Mn$^{2+}$ doped into QDs. As for the reason (1), the presence of Mn$^{2+}$ in the reaction solution might promote the deposition of QDs. However, our experimental results showed that the colour of the films loaded with Cd$_{1-x}$Mn$_x$Se QDs becomes lighter gradually with the increase of the x value, indicating that the amount of QDs is not increased evidently with the increasing Mn content in QDs. So the enhanced absorbance of the photoelectrodes mainly results from reason (2) rather than reason (1). In addition, it is also found that the absorption edges of the film loaded with CdMnSe QDs shift towards short wavelength (blue shift), which derives from the increase of the band gap ($E_g$) accordingly as shown in Fig. 2(b). Typically, dopant elements will create one fixed energy level, not much dependent on the doping level. However, it might be possible to have much more substitution here, which is not possible in conventional doping. According
to the previous work, the of Cd1−xMnxSe QDs is between those of MnSe and CdSe. The increase of Eg is possibly attributed to the high band gap of MnSe (~2.5 eV). In view of the quantum confinement effect, the increase of Eg is attributed to the rise of the conduction band energy (Ecb) of QDs to the high energy level. The Eg of QDs can be calculated by plotting (Ahν)2 against the photon energy (hν), where A is the absorbance, h is Planck’s constant, and ν is the photon frequency. From Fig. 2(b), the Eg of Cd0.8Mn0.2Se QDs is 2.07 eV, which is higher than the Eg of CdSe QDs. According to the band edge alignment of TiO2/CdS/CdSe (CdMnSe), CdS has a higher Ecb than that of CdSe. The Mn dopant could increase the Eg of CdSe, which facilitates the transfer of electrons from QDs to TiO2.

Fig. 3(a) shows the photoluminescence (PL) spectra of the TiO2 films loaded with CdSe and Cd0.8Mn0.2Se QDs, respectively. The results reveal that the PL of the film loaded with Cd0.8Mn0.2Se QDs is higher than that of the film loaded with CdSe QDs. The possible reason is attributed to the fact that the Mn2+ doped into QDs can cover an emission window similar to that of the current workhorse of intrinsic QDs emitters, leading to the increase of the PL of QDs. The increase of PL also boosts the emission quantum yield (QY) of QDs, which is helpful for producing more excitons. In addition, the dopant creates electronic states in the mid-gap region of the QDs, and thus alters the charge separation and recombination. In a typical PL experiment, a QD is excited with a light-source that provides photons with energy larger than the band-gap energy. Once the photons are absorbed, electrons and holes are formed with finite momenta in the conduction and valence bands, respectively. The emission of photons is derived from the recombination of the electrons and holes. The possible cause of the high PL emission value is that more excitons (electrons and holes) result in more recombination of electrons and holes to emit more photons. However, in the solar cells, the electrons are mainly transferred to electrodes instead of the recombination with holes. So the high PL intensity would boost high charge density in the solar cell. Fig. 3(b) shows the excited state electron radiative decay of the TiO2 films loaded with CdSe and Cd0.8Mn0.2Se QDs, respectively. The results display that the emission decay of CdMnSe QDs is shorter than that of CdSe QDs, which indicates that the PL lifetime of QDs can be slightly shortened by the Mn2+ dopant. The short-lived excited state of the QDs shows the increase of the injection kinetics of photocreated electrons in the semiconductor. So the Mn2+ dopant can accelerate the electron injection from QDs to TiO2. This result is consistent with the increase in the Ecb of CdMnSe QDs facilitating the transfer of electrons from QDs to TiO2.

Fig. 4(a) displays the impedance spectra of the QDSCs measured under dark conditions with a forward bias of –0.6 V. The fitting results of the impedance spectra are listed in Table 1. In Fig. 4(a), the two semicircles correspond to the electron injection at the counter electrode–electrolyte interface and transport in the electrolyte at high frequencies (Rct), and the electron transfer at the TiO2/QD/electrolyte interface and transport in the TiO2 film (Rs), respectively. The Rct is considered as the charge transfer resistance. The results show that the value of Rct of the Cd0.8Mn0.2Se sensitized solar cell (39.6 Ω) is much higher than that of the CdSe sensitized solar cell (29.3 Ω). In view of the increase of Rct, the electrons are difficult to recombine with the holes in the electrolyte, which results in the decrease of charge recombination. Although it is very difficult to find out the intrinsic cause of the increase of Rct, we believe the possible reason is that the Mn2+ dopant may modify the surface or the interface of QDs to increase the Rc and reduce the charge recombination. Fig. 4(b) shows the Bode plots of the QDSCs with different QDs. The curve peak of the spectrum can be used to determine the electron lifetime according to eqn (1).

\[ \tau_n = 1/(2\pi f_{\text{min}}) \]  

(1)

The corresponding results are listed in Table 1, revealing that the electron lifetime of the CdMnSe sensitized solar cell is 89.6 ms, which is twice that of the CdSe sensitized solar cell (41.5 ms). It is clear that the electron lifetime of the solar cell is prolonged by the Mn2+ doped into QDs. The electron lifetime (τn) is also proportional to Rct and is calculated by eqn (2).

\[ \tau_n = R_{\text{ct}}C_\mu \]  

(2)
where \( C_m \) is the corresponding chemical capacitance. Consequently, the employment of the Mn\(^{2+}\) dopant in QDs can enhance the charge recombination resistance and thus prolong the electron lifetime.

It is well known that for the solar cells, electron generation characteristics can be evaluated by the external quantum efficiency (EQE, or incident photon-to-current conversion efficiency, IPCE) and the absorbed photon to current conversion efficiency (APCE). Fig. 5(a) displays the EQE spectra of QDSCs assembled with CdSe and Cd\(_{0.8}\)Mn\(_{0.2}\)Se QDs, respectively. The maximum EQE of a Cd\(_{0.8}\)Mn\(_{0.2}\)Se sensitized solar cell reaches 74\% at 580 nm, which is enhanced by \( \approx 30\% \) compared to the maximum EQE of 58\% at 550 nm for a CdSe sensitized one. The EQE is substantially improved from visible to near infrared radiation region 800 nm. The EQE depends on both the absorption of light and the collection of charges. Once a photon has been absorbed and has generated an electron–hole pair, these charges must be separated and collected. The EQE can be estimated by light-harvesting efficiency (LHE), charge-transfer efficiency (\( \eta_{ct} \)), and charge-collection efficiency (\( \eta_{cc} \)), which is expressed by the following equation (eqn (3)).

\[
\text{EQE} = \text{LHE}\eta_{ct}\eta_{cc}
\] (3)

The LHE of the solar cell is consistent with the absorbance of the photoelectrode. From the result of the UV-visible spectra (as shown in Fig. 2(a)), the absorbance of Cd\(_{0.8}\)Mn\(_{0.2}\)Se QDs is much higher than that of CdSe QDs. The high absorbance indicates that a higher LHE can be obtained accordingly. In addition, Fig. 3(a) shows that the increase of PL of CdMnSe QDs can boost the exciton generation due to the improvement of QY. The effect of charge-transfer efficiency (\( \eta_{ct} \)) on EQE spectra is difficult to discuss, because there are not ideal measurements to estimate the efficiency for us. But we could deduce the \( \eta_{ct} \) by the excited state electron radiative decay of QDs, as shown in Fig. 3(b). In view of Fig. 2, the Mn\(^{2+}\) dopant could increase the \( E_{cb} \) of CdSe, which facilitates the electron transfer to TiO\(_2\). Fig. 3(b) shows that the electron injection from QDs to TiO\(_2\) can be accelerated by the Mn\(^{2+}\) dopant. So the increase of \( E_{cb} \) and electron injection kinetics is helpful for improving \( \eta_{ct} \). As for the charge-collection efficiency (\( \eta_{cc} \)), that is mainly contributed by the charge recombination. EIS results (Fig. 4) have revealed that the employment of the Mn\(^{2+}\) dopant in QDs can enhance the charge recombination resistance and thus prolong the electron lifetime. Both the drop in the charge recombination and the increase in electron lifetime can cause an enhancement in

<table>
<thead>
<tr>
<th>Samples</th>
<th>( R_1 (\Omega) )</th>
<th>( R_{ct} (\Omega) )</th>
<th>( \tau_n (\text{mS}) )</th>
</tr>
</thead>
<tbody>
<tr>
<td>CdSe</td>
<td>3.2</td>
<td>29.3</td>
<td>41.5</td>
</tr>
<tr>
<td>CdMnSe</td>
<td>3.6</td>
<td>39.6</td>
<td>89.6</td>
</tr>
</tbody>
</table>

Table 1 Electrochemical impedance results of QDSCs

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charge-collection efficiency ($\eta_{cc}$). Therefore, it can be deduced that the improved quantum efficiency of the solar cells is ascribed to the increased light-harvesting, charge-transfer and charge-collection efficiencies. Fig. 5(b) shows the APCE spectra of QDSCs assembled with CdSe and Cd$_{0.8}$Mn$_{0.2}$Se QDs, respectively. APCE is the absorbed photon to current conversion efficiency and shows how efficiently the absorbed photons are converted into current. It can be seen that the APCE value of the Cd$_{0.8}$Mn$_{0.2}$Se sensitized solar cell is much higher than that of the CdSe sensitized solar cell. APCE is obtained by dividing the IPCE number by the light-harvesting efficiency (LHE, 0–100%). So the increase of APCE is mainly attributed to the increase of $\eta_{ct}$ and $\eta_{cc}$.

Fig. 6 shows photocurrent density–voltage ($J$–$V$) characteristics of the solar cells measured under the illumination of one sun (AM 1.5, 100 mW cm$^{-2}$). The performance parameters of the solar cells are listed in Table 2. The Cd$_{0.8}$Mn$_{0.2}$Se sensitized solar cell exhibits a high performance: $J_{sc} = 19.15$ mA cm$^{-2}$, $V_{oc} = 0.58$ V, FF = 0.57 and $\eta = 6.33\%$. It can be seen that the $J_{sc}$ of the solar cell is improved evidently after Mn$^{2+}$ doping, which is the main cause of the improvement of the conversion efficiency. The remarkable increase of $J_{sc}$ is attributed to the excited charge characteristics, such as generation, injection or collection. The Mn$^{2+}$ ions doped into QDs increase the efficiencies of light-harvesting, charge-transfer and charge-collection, which results in the improvement of the EQE of the solar cell resulting in enhanced $J_{sc}$ and $\eta$. To the best of our knowledge, the $\eta$ of 6.33% is one of the highest values for CdSe quantum dot sensitized solar cells at this time.

### Table 2  Photovoltaic properties obtained from the $J$–$V$ curves using Cd$_{1-x}$Mn$_x$Se QDs as sensitizers

<table>
<thead>
<tr>
<th>Samples</th>
<th>$V_{oc}$ (V)</th>
<th>$J_{sc}$ (mA cm$^{-2}$)</th>
<th>FF</th>
<th>$\eta$ (%)</th>
</tr>
</thead>
<tbody>
<tr>
<td>CdSe</td>
<td>0.57</td>
<td>14.65</td>
<td>0.56</td>
<td>4.68 ± 0.22</td>
</tr>
<tr>
<td>CdMnSe</td>
<td>0.58</td>
<td>19.15</td>
<td>0.57</td>
<td>6.33 ± 0.35</td>
</tr>
</tbody>
</table>

3. Conclusion

The Cd$_{0.8}$Mn$_{0.2}$Se QDs were obtained by facile chemical bath deposition (CBD) and assembled to QDSCs. The Mn$^{2+}$ ions doped into QDs can increase the light harvesting efficiency to produce more excitons. In addition, the Mn$^{2+}$ dopant also raises the conduction band of CdSe, accelerates the exciton injection kinetics and reduces charge recombination, improving the charge transfer and collection. The increase of the efficiencies of light-harvesting, charge-transfer and charge-collection results in the improvement of the external quantum efficiency (EQE) of the solar cells. As a result, Cd$_{0.8}$Mn$_{0.2}$Se sensitized solar cells exhibited a high conversion efficiency ($\eta$) of 6.33%, which is 30% greater than that of the CdSe sensitized solar cell (4.68%). So the method of doping ions into QDs would be considered as an effective approach to prepare high efficiency QDSCs.

4. Experimental section

#### TiO$_2$ film fabrication

TiO$_2$ mesoporous films with a thickness of 10 ± 0.5 μm were prepared via doctor blading on the F:SnO$_2$ glass (FTO, 8 Ω square$^{-1}$) substrates using TiO$_2$ pastes composed of TiO$_2$ nanoparticles (Degussa P25), ethyl cellulose and a-terpineol. The as-received TiO$_2$ films were subjected to a sintering process in air at 500 °C for 30 min.

#### Cd$_{1-x}$Mn$_x$Se QD deposition

As a seed layer, CdS QDs were first deposited on the surface of TiO$_2$ nanoparticles by the successive ionic layer adsorption and reaction (SILAR) method. The detailed experimental procedure could be found in our previous work. And then, Cd$_{1-x}$Mn$_x$Se QDs were deposited on the CdS-coated TiO$_2$ films through a chemical bath deposition (CBD) method. The CdS-coated TiO$_2$ films were vertically immersed into an aqueous solution containing 0.1 M sodium selenosulphate (Na$_2$SeSO$_3$) aqueous solution, 0.1 M mixture of cadmium acetate Cd(CH$_3$COO)$_2$ and manganese acetate Mn(CH$_3$COO)$_2$, and 0.2 M trisodium salt of nitroliotriacetic acid (Na(CH$_3$COONa)$_3$) at room temperature for 3 hours. After that, a ZnS passivation layer was deposited by two SILAR cycles while being soaked in an aqueous solution containing 0.1 M zinc nitrate and 0.1 M sodium sulfide, which act as Zn$^{2+}$ and S$^{2-}$ sources, respectively.

#### Counter electrode and electrolyte

The Cu$_2$S film was used as the counter electrode in this study, which was prepared on the brass foil as follows: the brass foil was immersed into 37% HCl at 70 °C for 20 min, and then it was washed and dried. The etched brass foil was dipped into aqueous solution containing 1 M S and 1 M Na$_2$S to form a Cu$_2$S film. The electrolyte employed in this study was composed of 1 M S and 1 M Na$_2$S in deionized water.
Materials and QDSC characterization

An FEI Quan250FEG SEM system equipped with an energy-dispersive X-ray (EDX) spectrometer was employed to estimate the element contents. XPS spectra were collected using an ESCA 2000 spectrometer. The X-ray source was Al Kα and the x axis was fitted for the C 1s peak to have 284.6 eV. The removal of the background signal and integration of the peak was conducted using a VGX900-W system. The absorption spectra were recorded using a Shimadzu UV-3600 spectrophotometer. The photoluminescence (PL) spectra were recorded by using an excitation wavelength of 430 nm at room temperature using a Shimadzu luminescence spectrometer RF-5301PC. The photocurrent vs. voltage (J-V) characteristics of the solar cells were evaluated using simulated AM 1.5 sunlight with an output power of 100 mW cm⁻². The active area of the QDSCs was 0.1256 cm² as determined by a photo-mask. The external quantum efficiency (EQE) spectra were obtained in the range of 400–800 nm using a Keithley 2000 multimeter with illumination using a 300 W tungsten lamp with a Spectral Product DK240 monochromator. The electrochemical impedance spectroscopy (EIS) was carried out with use of an impedance analyzer (ZAHNER CIMPS) under dark conditions at a forward bias of 0.6 V.

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Notes and references